

RoHS compliant

> PIN 1, TAB (DRAIN)

PIN 2 (POWER

SOURCE)

Marking

C3M0021120K

C3M0021120K

Silicon Carbide Power MOSFET C3M™ MOSFET Technology N-Channel Enhancement Mode

Features

- 3rd generation SiC MOSFET technology
- Optimized package with separate driver source pin
- 8mm of creepage distance between drain and source
- High blocking voltage with low on-resistance
- High-speed switching with low capacitances
- Fast intrinsic diode with low reverse recovery (Q_{rr})
- Halogen free, RoHS compliant

Typical Applications

- Solar inverters
- EV motor drive
- High voltage DC/DC converters
- Switched mode power supplies
- Load switch

Benefits

Part Number

C3M0021120K

Reduce switching losses and minimize gate ringing

PIN 4 (GATE)

PIN 3

SOURCE)

Package

TO 247-4

(DRIVER C

- Higher system efficiency
- Reduce cooling requirements
- Increase power density
- Increase system switching frequency

Key Parameters

Parameter	Symbol	Min.	Тур.	Мах	Unit	Conditions	Note	
Drain - Source Voltage	V _{DS}			1200		T _c = 25°C		
Maximum Gate - Source Voltage	V _{GS(max)}	-8		+19	v	Transient		
Operational Gate-Source Voltage	V _{GS op}		-4/15			Static	Note 1	
DC Continuous Drain Current				100	A	$V_{_{GS}} = 15 \text{ V}, \text{ T}_{_{C}} = 25 \text{ °C}, \text{ T}_{_{J}} \le 175 \text{ °C}$	Fig. 19 Note 2	
	I _D			74		$V_{GS} = 15 \text{ V}, \text{ T}_{C} = 100 \text{ °C}, \text{ T}_{J} \le 175 \text{ °C}$		
Pulsed Drain Current	I _{DM}			200		t_{Pmax} limited by T_{jmax} $V_{cS} = 15V, T_c = 25 °C$	Fig. 22	
Power Dissipation	P _D			469	w	$T_{c} = 25^{\circ}C, T_{J} = 175^{\circ}C$	Fig. 20	
Operating Junction and Storage Temperature	T _J , T _{stg}			-40 to +175	°C			
Solder Temperature	TL			260		According to JEDEC J-STD-020		
Mounting Torque	M _D			1 8.8	Nm Ibf-in	M3 or 6-32 screw		

Note (1): Recommended turn-on gate voltage is 15V with ±5% regulation tolerance, see Application Note PRD-04814 for additional details Note (2): Verified by design

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Electrical Characteristics ($T_c = 25^{\circ}C$ unless otherwise specified)

	Symbol	Min.	Тур.	Max.	Unit	Test Conditions	Note	
Drain-Source Breakdown Voltage	V _{(BR)DSS}	1200	-	-		$V_{GS} = 0 \text{ V}, I_{D} = 100 \mu\text{A}$		
		1.8	2.5	3.6	V	$V_{DS} = V_{GS}$, $I_{D} = 17.7$ mA	- Fig. 11	
Gate Threshold Voltage	V _{GS(th)}	_	2.0	_]	$V_{DS} = V_{GS}$, $I_D = 17.7$ mA, $T_J = 175^{\circ}$ C	FIg. 11	
Zero Gate Voltage Drain Current	I _{DSS}	_	1	50		V _{DS} = 1200 V, V _{GS} = 0 V		
Gate-Source Leakage Current	I _{GSS}	—	10	250	nA	$V_{GS} = 15 V, V_{DS} = 0 V$		
		_	21	28.8		$V_{GS} = 15 \text{ V}, I_{D} = 50 \text{ A}$	Fig. 4, 5, 6	
Drain-Source On-State Resistance	R _{DS(on)}	_	38	-	mΩ	$V_{GS} = 15 \text{ V}, I_{D} = 50 \text{ A}, T_{J} = 175^{\circ}\text{C}$		
T			35		s	$V_{DS} = 20 \text{ V}, I_{DS} = 50 \text{ A}$		
Transconductance	g _{fs}	_	33	_	3	V _{DS} = 20 V, I _{DS} = 50 A, T _J = 175°C	Fig. 7	
Input Capacitance	C _{iss}	_	4818	_			Fig. 17, 18	
Output Capacitance	C _{oss}	_	180	_	pF	$V_{GS} = 0 V, V_{DS} = 1000 V$		
Reverse Transfer Capacitance	C _{rss}	-	12	-		f = 100 khz V _{AC} = 25 mV		
C _{oss} Stored Energy	E _{oss}	-	99	-	μJ		Fig. 16	
Turn-On Switching Energy (SiC Diode FWD)	Eon	-	0.69	-			Fig.	
Turn Off Switching Energy (SiC Diode FWD)	E _{off}	_	0.42	-]	$V_{DS} = 800 \text{ V}, V_{GS} = -4 \text{ V}/+15 \text{ V}, I_{D} = 50 \text{ A},$		
Turn-On Switching Energy (Body Diode FWD)	E _{on}	_	1.58	_	mJ $R_{G(ext)} = 2.5 \Omega, L = 157 \mu H,$ T _J = 175°C		26, 29	
Turn Off Switching Energy (Body Diode FWD)	E _{off}	-	0.34	_]			
Turn-On Delay Time	t _{d(on)}	_	29	_			Fig. 27	
Rise Time	tr	_	33	_	1	$V_{DD} = 800 \text{ V}, V_{GS} = -4 \text{ V}/15 \text{ V}$ $R_{G(ext)} = 2.5 \Omega, L = 157 \text{ uH}$		
Turn-Off Delay Time	t _{d(off)}	_	57	_	ns	Timing relative to V _{DS} inductive load		
Fall Time	t _f	_	14	_	1	load		
Internal Gate Resistance	R _{G(int)}	_	3.3	_	Ω	f = 1 MHz, V _{AC} = 25 mV		
Gate to Source Charge	Q _{gs}	_	49	_			Fig. 12	
Gate to Drain Charge	Q _{gd}	_	50	_	nC	$V_{DS} = 800 \text{ V}, V_{GS} = -4 \text{ V}/15 \text{ V}$ $I_D = 50 \text{ A}$		
Total Gate Charge	Qg	_	162	_	Per IEC60747-8-4 pg 21			

Note (3): $C_{o(er)}$, a lumped capactiance that gives the same stored energy as Coss while Vds is rising from 0 to 800V $C_{o(tr)}$, a lumped capacitance that gives the same stored time as Coss while Vds is rising from 0 to 800V

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Reverse Diode Characteristics ($T_c = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Тур.	Max.	Unit	Test Conditions	Notes	
		4.6	_	V	$V_{GS} = -4 V, I_{SD} = 25 A, T_{J} = 25^{\circ}C$	Fig.	
Diode Forward Voltage	V _{SD}	4.2			$V_{GS} = -4 V$, $I_{SD} = 25 A$, $T_{J} = 175^{\circ}C$	8, 9, 10	
Continuous Diode Forward Current	Is	_	90		$V_{GS} = -4 V, T_{C} = 25^{\circ}C$		
Diode pulse Current	I _{SM}	_	200	A	V _{GS} = -4 V, pulse width t _P limited by T _{jmax}		
Reverse Recover Time	t _{rr}	34	[_				
Reverse Recovery Charge	Qrr	928	_	ns	$V_{GS} = -4 V, I_{SD} = 50 A, V_{R} = 800 V$ dif/dt = 2600 A/µs, T _J = 175°C		
Peak Reverse Recovery Current	I _{RRM}	42	_	nC			

Thermal Characteristics

Parameter	Symbol	Тур.	Unit	Note
Thermal Resistance from Junction to Case	$R_{ extsf{ heta}JC}$	0.32	00.000	Fig. 21
Thermal Resistance From Junction to Ambient	$R_{ heta JA}$	40	°C/W	

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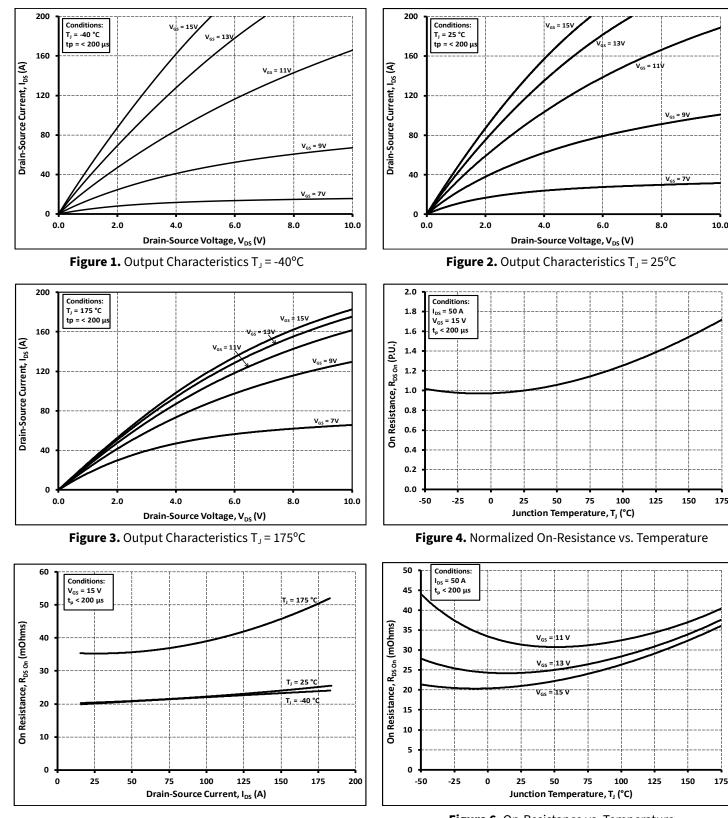


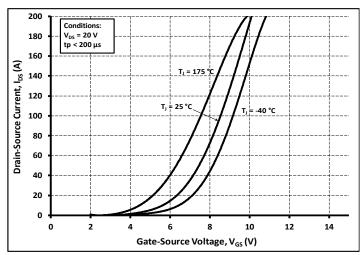
Figure 5. On-Resistance vs. Drain Current For Various Temperatures Figure 6. On-Resistance vs. Temperature For Various Gate Voltage

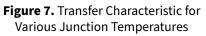
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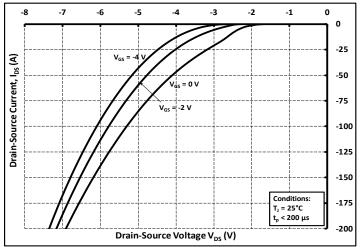
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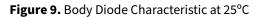
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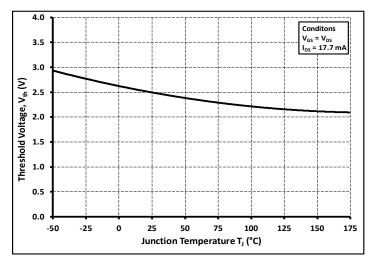


Figure 11. Threshold Voltage vs. Temperature

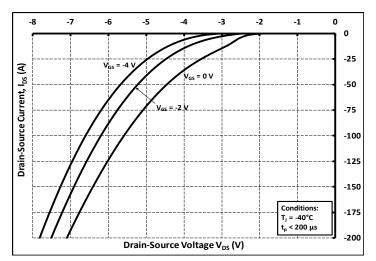


Figure 8. Body Diode Characteristic at -40°C

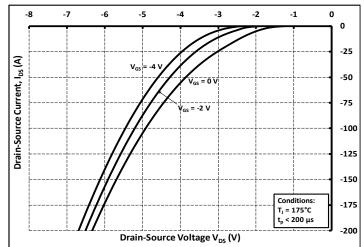


Figure 10. Body Diode Characteristic at 175°C

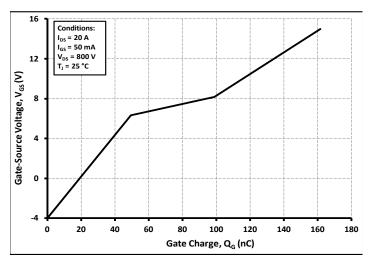


Figure 12. Gate Charge Characteristics

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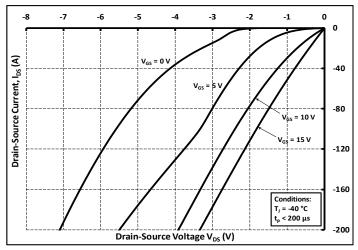


Figure 13. 3rd Quadrant Characteristic at -40°C

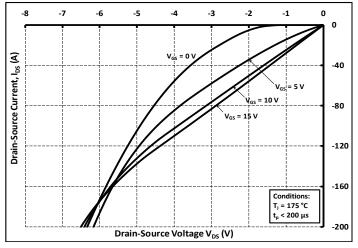


Figure 15. 3rd Quadrant Characteristic at 175°C

С

150

50

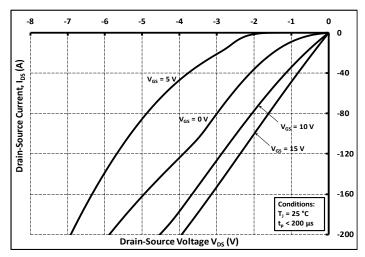


Figure 14. 3rd Quadrant Characteristic at 25°C

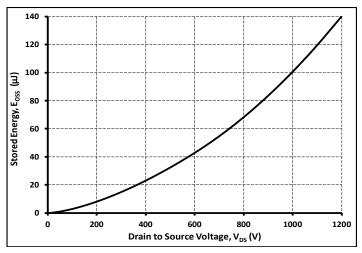


Figure 16. Output Capacitor Stored Energy

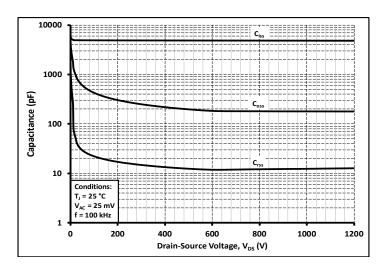
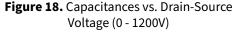


Figure 17. Capacitances vs. Drain-Source Voltage (0 - 200V)

100

Drain-Source Voltage, V_{DS} (V)



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10000

1000

100

10

1

0

Conditions

T, = 25 °C

= 25 m

= 100 kHz

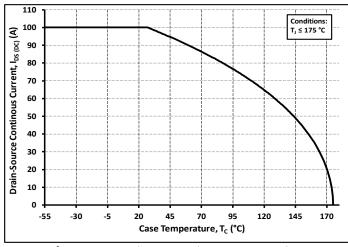
Capacitance (pF)

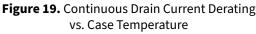
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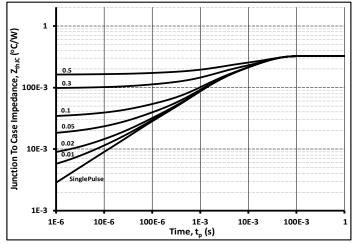
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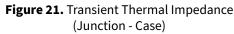
200

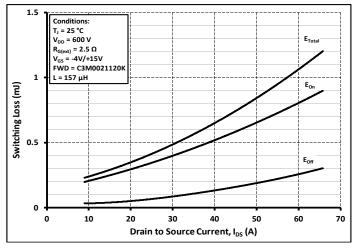


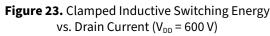












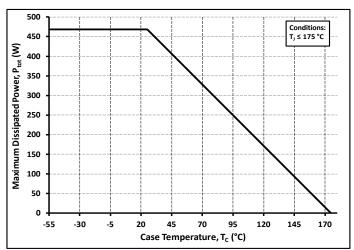


Figure 20. Maximum Power Dissipation Derating vs. Case Temperature

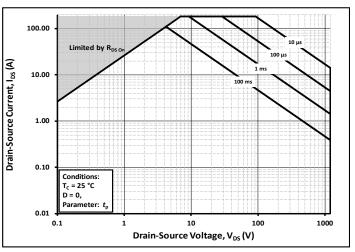


Figure 22. Safe Operating Area

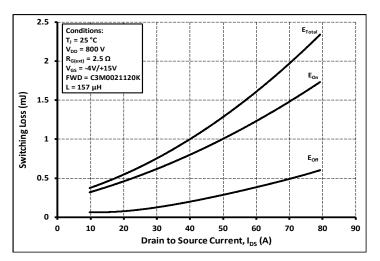


Figure 24. Clamped Inductive Switching Energy vs. Drain Current (V_{DD} = 800 V)

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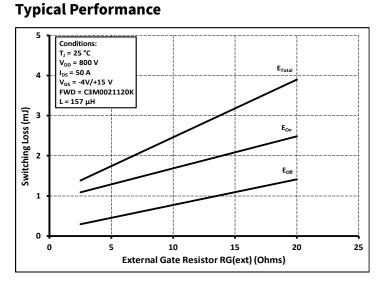


Figure 25. Clamped Inductive Switching Energy vs. R_{G(ext)}

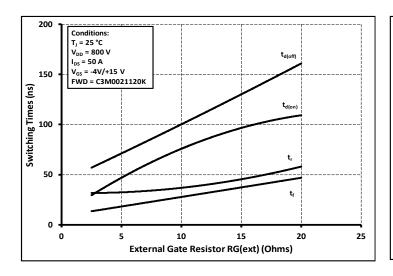


Figure 27. Switching Times vs. R_{G(ext)}

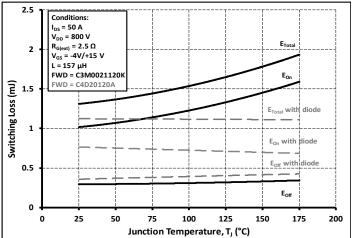


Figure 26. Clamped Inductive Switching Energy vs. Temperature

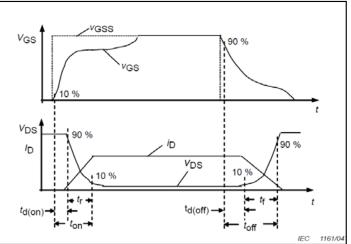


Figure 28. Switching Times Definition

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Test Circuit Schematic¹

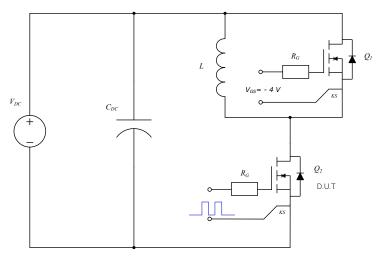


Figure 29. Clamped Inductive Switching Waveform Test Circuit

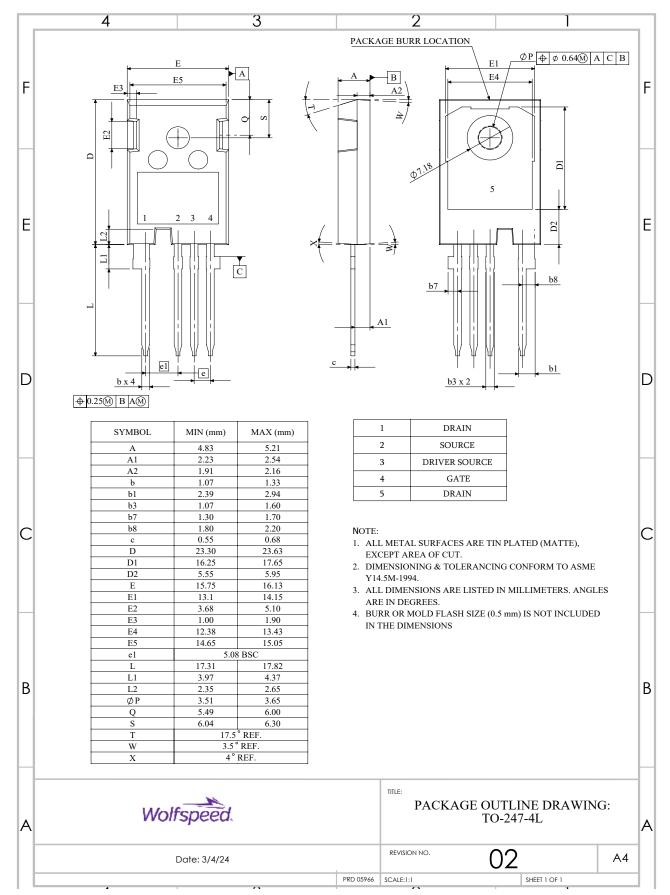
Note:

¹ Turn-off and Turn-on switching energy and timing values measured using SiC MOSFET Body Diode as shown above.

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Package Dimensions – Package TO-247-4L



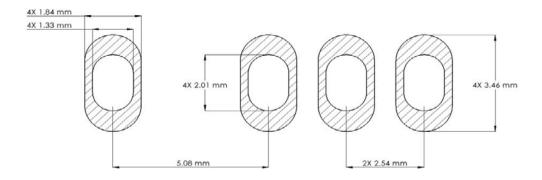
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Recommended Solder Pad Layout



Revision History

Document Version	Date of Release	Description of Changes				
1	March-2023	N/A				
2	December-2023	Updated Package Image, solder pad layout, added revision histor Table 1 layout revised				
3	September - 2024	Legal Disclaimer, POD, Diode Pulse Current Symbol				

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